High Voltage, High Current Darlington Transistor Arrays

The seven NPN Darlington connected transistors in these arrays are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 500 mA permit them to drive incandescent lamps.

The MC1413, B with a 2.7 k Ω series input resistor is well suited for systems utilizing a 5.0 V TTL or CMOS Logic.

Features

- Pb–Free Packages are Available*
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes

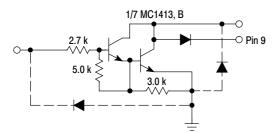


Figure 1. Representative Schematic Diagram

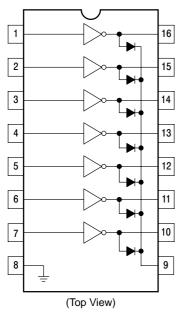
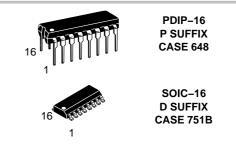


Figure 2. PIN CONNECTIONS



ON Semiconductor®

http://onsemi.com



ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------|----------------------|-----------------------|
| MC1413D | SOIC-16 | 48 Units/Rail |
| MC1413DG | SOIC-16 (Pb-Free) | 48 Units/Tube |
| MC1413DR2 | SOIC-16 | 2500 Tape & Reel |
| MC1413DR2G | SOIC-16 (Pb-Free) | 2500 Tape & Reel |
| MC1413P | PDIP-16 | 25 Units/Rail |
| MC1413PG | PDIP-16 (Pb-Free) | 25 Units/Rail |
| MC1413BD | SOIC-16 | 48 Units/Rail |
| MC1413BDG | SOIC-16 (Pb-Free) | 48 Units/Rail |
| MC1413BDR2 | SOIC-16 | 2500 Tape & Reel |
| MC1413BDR2G | SOIC-16 (Pb-Free) | 2500 Tape & Reel |
| MC1413BP | PDIP-16 | 25 Units/Rail |
| MC1413BPG | PDIP-16 (Pb-Free) | 25 Units/Rail |
| NCV1413BDR2 | SOIC-16 | 2500 Tape & Reel |
| NCV1413BDR2G | SOIC-16 (Pb-Free) | 2500 Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 5 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS ($T_A = 25^{\circ}C$, and rating apply to any one device in the package, unless otherwise noted.)

| Rating | Symbol | Value | Unit |
|---|------------------|---|------|
| Output Voltage | Vo | 50 | V |
| Input Voltage | VI | 30 | V |
| Collector Current – Continuous | ۱ _C | 500 | mA |
| Base Current – Continuous | اB | 25 | mA |
| Operating Ambient Temperature Range MC1413 MC1413B NCV1413B | T _A | -20 to +85 -40 to +85 -40 to +125 | °C |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |
| Junction Temperature | TJ | 150 | °C |
| Thermal Resistance, Junction-to-Ambient Case 648, P Suffix Case 751B, D Suffix | R _{θJA} | 67 100 | °C/W |
| Thermal Resistance, Junction-to-Case Case 648, P Suffix Case 751B, D Suffix | R _{θJC} | 22 20 | °C/W |
| Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM) Charged Device Model (CDM) | ESD | 2000 400 1500 | V |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

| Characteristic | | Symbol | Min | Тур | Max | Unit |
|--|--|----------------------|-------------|---------------------|-------------------|------|
| Output Leakage Current $(V_O = 50 \text{ V}, T_A = +85^{\circ}\text{C})$ $(V_O = 50 \text{ V}, T_A = +25^{\circ}\text{C})$ | All Types All Types | I _{CEX} | | - | 100 50 | μΑ |
| Collector–Emitter Saturation Voltage ($I_C = 350 \text{ mA}, I_B = 500 \mu A$) ($I_C = 200 \text{ mA}, I_B = 350 \mu A$) ($I_C = 100 \text{ mA}, I_B = 250 \mu A$) | All Types All Types All Types | V _{CE(sat)} | - - - | 1.1 0.95 0.85 | 1.6 1.3 1.1 | V |
| Input Current – On Condition $(V_1 = 3.85 V)$ | MC1413, B | I _{I(on)} | - | 0.93 | 1.35 | mA |
| Input Voltage – On Condition $(V_{CE} = 2.0 \text{ V}, I_C = 200 \text{ mA})$ $(V_{CE} = 2.0 \text{ V}, I_C = 250 \text{ mA})$ $(V_{CE} = 2.0 \text{ V}, I_C = 300 \text{ mA})$ | MC1413, B MC1413, B MC1413, B | V _{I(on)} | - - - | - - - | 2.4 2.7 3.0 | V |
| Input Current – Off Condition ($I_C = 500 \ \mu A, T_A = 85^{\circ}C$) | All Types | I _{I(off)} | 50 | 100 | - | μΑ |
| DC Current Gain $(V_{CE} = 2.0 \text{ V}, I_C = 350 \text{ mA})$ | | h _{FE} | 1000 | - | - | - |
| Input Capacitance | | Cl | - | 15 | 30 | pF |
| Turn–On Delay Time (50% E _I to 50% E _O) | | t _{on} | - | 0.25 | 1.0 | μs |
| Turn–Off Delay Time (50% E _I to 50% E _O) | | t _{off} | - | 0.25 | 1.0 | μs |
| Clamp Diode Leakage Current (V _R = 50 V) | T _A = +25°C T _A = +85°C | Ι _R | _ _ | - | 50 100 | μΑ |
| Clamp Diode Forward Voltage (I _F = 350 mA) | | VF | - | 1.5 | 2.0 | V |

ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise noted)

NOTE: NCV1413B T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

TYPICAL PERFORMANCE CURVES – $T_A = 25^{\circ}C$

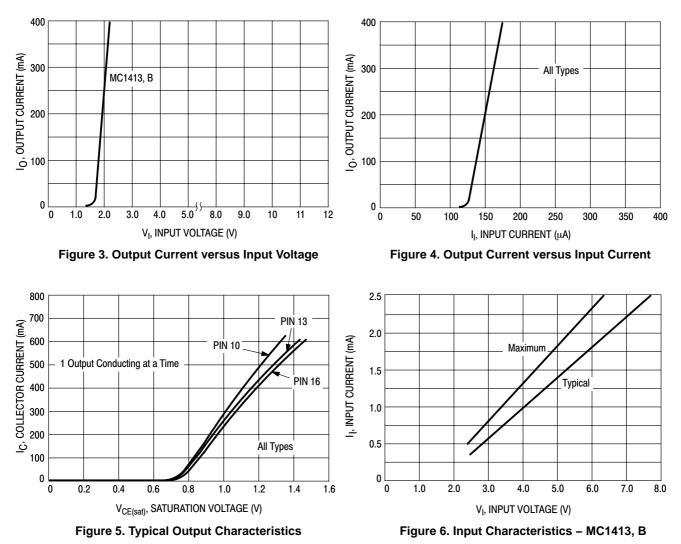


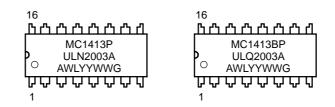




Figure 7. Maximum Collector Current versus Duty Cycle (and Number of Drivers in Use)

MARKING DIAGRAMS





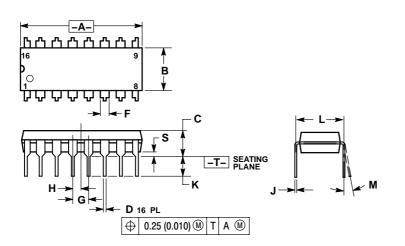
SOIC-16 D SUFFIX CASE 751B

| 16 | 16 | 16 |
|------------------------|------------------------|----------------------|
| <u>A A A A A A A A</u> | <u>, A A A A A A A</u> | <u> </u> |
| MC1413DG AWLYWW | MC1413BDG AWLYWW | NCV1413BDG AWLYWW |
| <u> </u> | <u> </u> | <u> </u> |

- A = Assembly Location WL = Wafer Lot YY, Y = Year
- WW = Work Week
- G = Pb-Free Package

PACKAGE DIMENSIONS

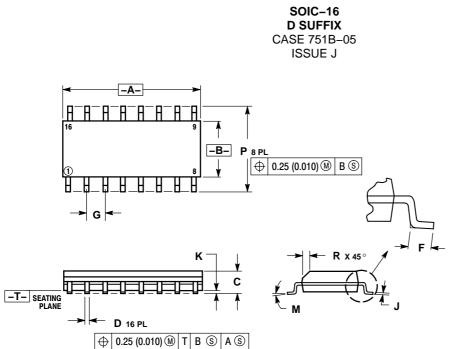
PDIP-16 **P SUFFIX** CASE 648-08 ISSUE T



- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

| | INCHES | | MILLIN | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.740 | 0.770 | 18.80 | 19.55 |
| В | 0.250 | 0.270 | 6.35 | 6.85 |
| С | 0.145 | 0.175 | 3.69 | 4.44 |
| D | 0.015 | 0.021 | 0.39 | 0.53 |
| F | 0.040 | 0.70 | 1.02 | 1.77 |
| G | 0.100 | BSC | 2.54 BSC | |
| Н | 0.050 BSC | | 1.27 BSC | |
| J | 0.008 | 0.015 | 0.21 | 0.38 |
| ĸ | 0.110 | 0.130 | 2.80 | 3.30 |
| L | 0.295 | 0.305 | 7.50 | 7.74 |
| м | 0 ° | 10 ° | 0 ° | 10 ° |
| S | 0.020 | 0.040 | 0.51 | 1.01 |

PACKAGE DIMENSIONS



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.05) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIMETERS | | INCHES | |
|-----|-------------|----------|--------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 9.80 | 10.00 | 0.386 | 0.393 |
| В | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 | 1.27 BSC | | BSC |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| М | 0 ° | 7° | 0 ° | 7° |
| Р | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

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